

February 1992 Revised June 2001

74LVQ245

Low Voltage Octal Bidirectional Transceiver with 3-STATE Outputs

General Description

The LVQ245 contains eight non-inverting bidirectional buffers with 3-STATE outputs and is intended for bus-oriented applications. Current sinking capability is 12 mA at both the A and B ports. The Transmit/Receive ($\overline{T/R}$) input determines the direction of data flow through the bidirectional transceiver. Transmit (active-HIGH) enables data from A ports to B ports; Receive (active-LOW) enables data from B ports to A ports. The Output Enable input, when HIGH, disables both A and B ports by placing them in a HIGH Z condition.

Features

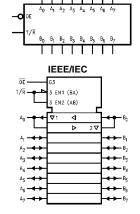
- Ideal for low power/low noise 3.3V applications
- Implements patented EMI reduction circuitry
- Available in SOIC JEDEC, SOIC EIAJ and QSOP packages
- Guaranteed simultaneous switching noise level and dynamic threshold performance
- Improved latch-up immunity
- \blacksquare Guaranteed incident wave switching into 75 $\!\Omega$
- 4 kV minimum ESD immunity

Ordering Code

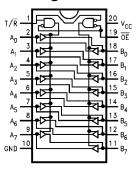
Order Number	Package Number	Package Description		
74LVQ245SC	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide		
74LVQ245SJ	M20D	20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide		
74LVQ245QSC	MQA20	20-Lead Quarter Size Outline Package (QSOP), JEDEC MO-137, 0.150" Wide		

Devices also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

Logic Symbols



Connection Diagram



Truth Table

Inp	uts	Outputs		
OE	T/R	Outputs		
L	L	Bus B Data to Bus A		
L	Н	Bus A Data to Bus B		
Н	Χ	HIGH-Z State		
H - HIGH Voltage Level I - LOW Voltage Level X - Immaterial				

Pin Descriptions

Pin Names	Description			
OE	Output Enable Inputs			
T/R	Transmit/Receive Input			
A ₀ -A ₇	Side A Inputs or			
	3-STATE Outputs			
B ₀ -B ₇	Side B Inputs or			
	3-STATE Outputs			

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Absolute Maximum Ratings(Note 1)

Conditions (Note 2)

Supply Voltage (V_{CC}) -0.5V to +7.0V

DC Input Diode Current (I_{IK})

 $\begin{array}{ccc} \text{V}_{\text{I}} = -0.5 \text{V} & -20 \text{ mA} \\ \text{V}_{\text{I}} = \text{V}_{\text{CC}} + 0.5 \text{V} & +20 \text{ mA} \\ \text{DC Input Voltage (V}_{\text{I}}) & -0.5 \text{V to V}_{\text{CC}} + 0.5 \text{V} \end{array}$

DC Output Diode Current (I_{OK})

 $V_{O} = -0.5V$ -20 mA $V_{O} = V_{CC} + 0.5V$ +20 mA

DC Output Voltage (V_O) -0.5V to $V_{CC} + 0.5V$

DC Output Source

or Sink Current (I_O) ±50 mA

DC V_{CC} or Ground Current

 $\begin{array}{ll} (\rm I_{CC} \ or \ I_{GND}) & \pm 400 \ mA \\ \\ Storage \ Temperature \ (T_{STG}) & -65^{\circ}C \ to +150^{\circ}C \end{array}$

DC Latch-Up Source or

Sink Current ±300 mA

Minimum Input Edge Rate (ΔV/Δt)

Recommended Operating

V_{IN} from 0.8V to 2.0V

 $V_{CC} @ 3.0V$ 125 mV/ns

Note 1: The "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the absolute maximum ratings. The "Recommended Operating Conditions" table will define the conditions

for actual device operation.

Note 2: Unused inputs must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

Symbol	Parameter	v _{cc}	T _A = +25°C		$T_A = -40^{\circ}C \text{ to } +85^{\circ}C$	Units	Conditions
		(V)	Тур	Gua	ranteed Limits	Units	Conditions
V _{IH}	Minimum High Level Input Voltage	3.0	1.5	2.0	2.0	V	V _{OUT} = 0.1V or V _{CC} - 0.1V
V _{IL}	Maximum Low Level Input Voltage	3.0	1.5	0.8	0.8	٧	V _{OUT} = 0.1V or V _{CC} - 0.1V
V _{OH}	Minimum High Level	3.0	2.99	2.9	2.9	V	I _{OUT} = -50 μA
	Output Voltage	3.0		2.58	2.48	V	$V_{IN} = V_{IL}$ or V_{IH} (Note 3) $I_{OH} = -12 \text{ mA}$
V _{OL}	Maximum Low Level	3.0	0.002	0.1	0.1	V	I _{OUT} = 50 μA
	Output Voltage	3.0		0.36	0.44	V	$V_{IN} = V_{IL} \text{ or } V_{IH} \text{ (Note 3)}$ $I_{OL} = +12 \text{ mA}$
I _{IN}	Maximum Input Leakage Current	3.6		±0.1	±1.0	μΑ	$V_I = V_{CC}$, GND
I _{OLD}	Minimum Dynamic	3.6			36	mA	V _{OLD} = 0.8V Max (Note 5)
I _{OHD}	Output Current (Note 4)	3.6			-25	mA	V _{OHD} = 2.0V Min (Note 5)
I _{CC}	Maximum Quiescent Supply Current	3.6		4.0	40.0	μА	$V_{IN} = V_{CC}$ or GND
l _{OZT}	Maximum I/O Leakage Current	3.6		±0.3	±3.0	μА	$\begin{aligned} & V_{I}\left(\overline{OE}\right) = V_{IL}, V_{IH} \\ & V_{I} = V_{CC}, GND \\ & V_{O} = V_{CC}, GND \end{aligned}$
V _{OLP}	Quiet Output Maximum Dynamic V _{OL}	3.3	0.5	0.8		V	(Note 6)(Note 7)
V _{OLV}	Quiet Output Minimum Dynamic V _{OL}	3.3	-0.5	-0.8		V	(Note 6)(Note 7)
V _{IHD}	Maximum High Level Dynamic Input Voltage	3.3	1.6	2.0		V	(Note 6)(Note 8)
V _{ILD}	Maximum Low Level Dynamic Input Voltage	3.3	1.7	0.8		V	(Note 6)(Note 8)

Note 3: All outputs loaded: thresholds on input associated with output under test.

 $\textbf{Note 4:} \ \ \text{Maximum test duration 2.0 ms, one output loaded at a time.}$

Note 5: Incident wave switching on transmission lines with impedances as low as 75Ω for commercial temperature range is guaranteed for 74LVQ.

Note 6: Worst case package.

Note 7: Max number of outputs defined as (n). Data inputs are driven 0V to 3.3V; one output at GND.

Note 8: Max number of Data Inputs (n) switching. (n - 1) inputs switching 0V to 3.3V. Input-under-test switching: 3.3V to threshold (V_{ILD}), 0V to threshold (V_{IHD}), f = 1 MHz.

AC Electrical Characteristics

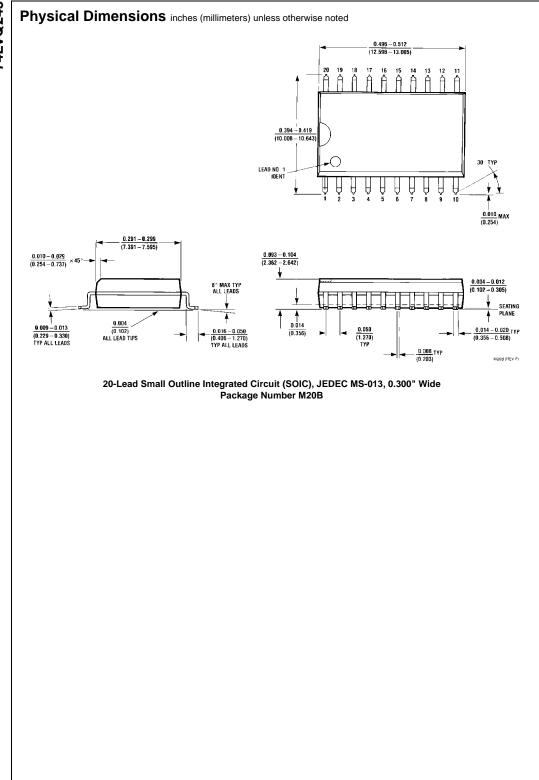
Symbol	Parameter	v	$T_A = +25$ °C $C_L = 50 \text{ pF}$			$T_A = -40^{\circ}\text{C to } +85^{\circ}\text{C}$ $C_L = 50 \text{ pF}$		Units
Symbol Parameter		V _{CC}						Units
		(V)	Min	Тур	Max	Min	Max	
t _{PHL}	Propagation Delay	2.7	2.0	9.0	14.0	2.0	15.0	ns
t _{PLH}		3.3 ± 0.3	2.0	7.5	10.0	2.0	10.5	115
t _{PZL}	Output Enable Time	2.7	3.0	10.2	18.3	3.0	19.0	ns
t _{PZH}		3.3 ± 0.3	3.0	8.5	13.0	3.0	13.5	115
t _{PHZ}	Output Disable Time	2.7	1.0	10.2	20.4	1.0	21.0	
t _{PLZ}		3.3 ± 0.3	1.0	8.5	14.5	1.0	15.0	ns
toshl	Output to Output	2.7		1.0	1.5		1.5	no
toslh	Skew (Note 9)	3.3 ± 0.3		1.0	1.5		1.5	ns

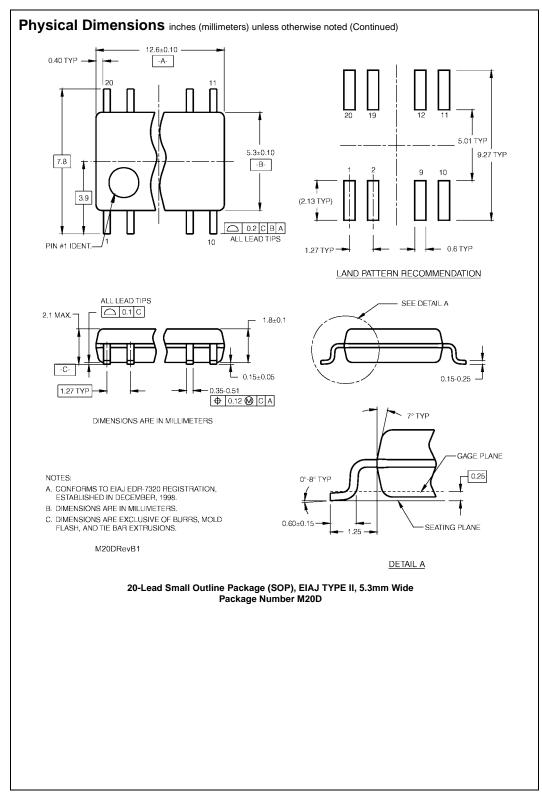
Note 9: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}). Parameter guaranteed by design.

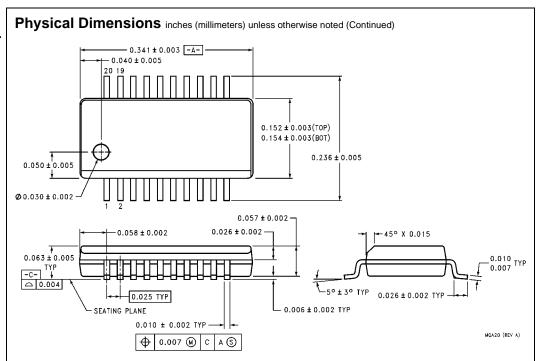
Capacitance

Symbol	Parameter	Тур	Units	Conditions
C _{IN}	Input Capacitance	4.5	pF	V _{CC} = Open
C _{I/O}	Input/Output Capacitance	15	pF	V _{CC} = 3.3V
C _{PD} (Note 10)	Power Dissipation Capacitance	67	pF	$V_{CC} = 3.3V$

Note 10: C_{PD} is measured at 10 MHz.







20-Lead Quarter Size Outline Package (QSOP), JEDEC MO-137, 0.150" Wide Package Number MQA20

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